

7-Unit 400mA Darlington Transistor Array

IR2411

T-52-13-45

# IR2411 7-Unit 400mA Darlington Transistor Array

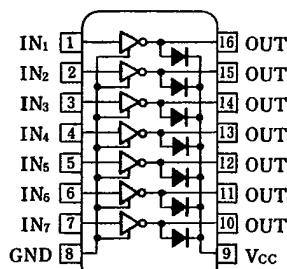
## Description

The IR2411 is a 7-circuit driver. The internal clamping diodes enable the IC to drive the inductive load directly.

## Features

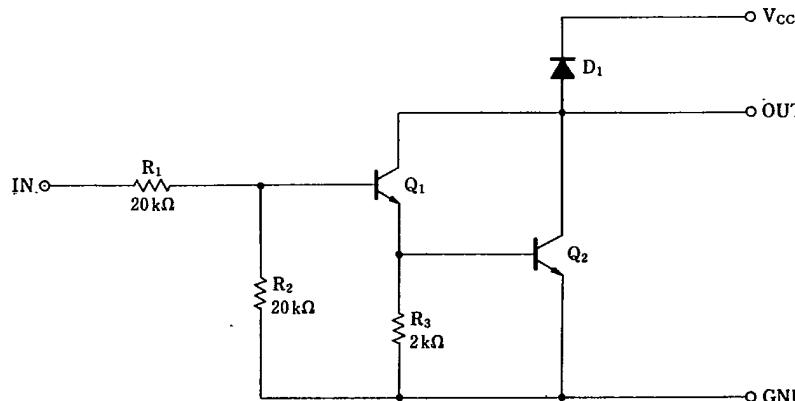
1. High output current,  $I_{OUT} = 400\text{mA}$  (MAX.)
2. High output breakdown voltage  
 $BV_{CEO} = 45\text{V}$  (MAX.)
3. Directly driven by MOS output
4. Internal output clamping diode
5. Darlington construction
6. 16-pin dual-in-line package

## Pin Connections



Top View

## Equivalent Circuit



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**Absolute Maximum Ratings**

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		45	V
Output current* <sup>1</sup>	I <sub>OUT</sub>	Each circuit	400	mA
Input voltage	V <sub>IN</sub>		-0.5~45	V
Breakdown voltage between collector-base	BV <sub>CBO</sub>		45	V
Breakdown voltage between collector-emitter	BV <sub>CEO</sub>		45	V
Forward current	I <sub>F</sub>	Applies to clamp diode	40	mA
Surge current	I <sub>surge</sub>	Applies to clamp diode	4000	mA
Load inductance	L <sub>L</sub>		100	mH
Power dissipation	P <sub>D</sub>	T <sub>a</sub> ≤25°C	650	mW
P <sub>D</sub> derating ratio	ΔP <sub>D</sub> /°C	T <sub>a</sub> >25°C	6.5	mW/°C
Operating temperature	T <sub>opr</sub>		-25~+75	°C
Storage temperature	T <sub>stg</sub>		-55~+125	°C



\*1 Duty cycle 10% or less, repetitive frequency 10Hz or more.

**Recommended Operating Conditions**

Parameter	Symbol	Condition	Rating	Unit
Max. output voltage	V <sub>OM</sub>		45	V
Operating temperature	T <sub>opr</sub>		-20~+75	°C
Output current* <sup>2</sup>	I <sub>OUT</sub>	at 10% duty	0~400	mA
		at 50% duty	0~150	

\*2 Repetitive frequency 10Hz or more.

**Electrical Characteristics**

(Ta = -25~+75°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	V <sub>CC</sub>				45	V
ON-state input current	I <sub>I ON</sub>	V <sub>IN</sub> =17V, I <sub>OUT</sub> =0mA		0.8	1.5	mA
ON-state output current	V <sub>O ON1</sub>	V <sub>IN</sub> =13V, I <sub>OUT</sub> =400mA			2.2	V
	V <sub>O ON2</sub>	V <sub>IN</sub> =13V, I <sub>OUT</sub> =200mA			1.4	
OFF-state output current	I <sub>O OFF</sub>	V <sub>IN</sub> =0V, V <sub>OUT</sub> =45V			100	μA
Diode forward voltage	V <sub>F</sub>	I <sub>F</sub> =400mA			2.2	V
Diode leakage current	I <sub>R</sub>	V <sub>R</sub> =45V			100	μA
DC current amplitude	h <sub>FE</sub>	V <sub>CE</sub> =2.5V, I <sub>OUT</sub> =300mA	1,000			
Sustaining voltage	V <sub>CERSUS</sub>	I <sub>OUT</sub> =10mA			45	V
Input voltage	V <sub>IN</sub>	I <sub>OUT</sub> =100mA			4	V

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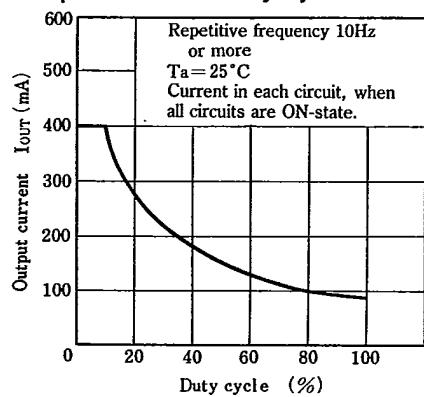
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**■ Electrical Characteristic Curve****Output current—Duty cycle Characteristics**

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